



BGU8051

Low noise high linearity amplifier

Rev. 7 — 8 June 2017

Product data sheet
COMPANY PUBLIC

1 General description

The BGU8051 is, also known as the BTS1001L, a low noise high linearity amplifier for wireless infrastructure applications, equipped with fast shutdown to support TDD systems. The LNA has a high input and output return loss and is designed to operate between 0.3 GHz and 1.5 GHz. It is housed in a 2 mm × 2 mm × 0.75 mm 8-terminal plastic thin small outline package. The LNA is ESD protected on all terminals.

2 Features and benefits

- Low noise performance: NF = 0.43 dB
- High linearity performance: IP_{3O} = 39 dBm
- High input return loss > 15 dB
- High output return loss > 20 dB
- Unconditionally stable
- Programmable bias current (via resistor)
- Small 8-terminal leadless package 2 mm × 2 mm × 0.75 mm
- ESD protection on all terminals
- Moisture sensitivity level 1
- Fast shut down to support TDD systems
- 3 V to 5 V single supply

3 Applications

- Wireless infrastructure
- Low noise and high linearity applications
- LTE, W-CDMA, CDMA, GSM
- General-purpose wireless applications
- TDD or FDD systems
- Suitable for small cells



4 Quick reference data

Table 1. Quick reference data

$f = 900\text{ MHz}$, $V_{CC} = 5\text{ V}$, $T_{amb} = 25\text{ }^\circ\text{C}$, input and output $50\ \Omega$; $R_{bias} = 5.1\text{ k}\Omega$; unless otherwise specified. All RF parameters are measured in an application board as shown in [Figure 16](#) with components listed in [Table 9](#) optimized for $f = 900\text{ MHz}$.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
I_{CC}	supply current	on state	36	48	60	mA
		off state	-	2.8	-	mA
G_{ass}	associated gain	on state	17	18.3	20	dB
		off state	-	-21	-	dB
NF	noise figure		-	0.43	0.63	dB
$P_{L(1dB)}$	output power at 1 dB gain compression		-	19	-	dBm
$IP3O$	output third-order intercept point	2-tone; tone spacing = 1 MHz; $P_i = -15\text{ dBm}$ per tone	35	39	-	dBm

5 Ordering information

Table 2. Ordering information

Type number	Package		Version
	Name	Description	
BGU8051	HWSO8	plastic thermal enhanced very very thin small outline package; no leads; 8 terminals; body $2 \times 2 \times 0.75\text{ mm}$	SOT1327-1

6 Block diagram

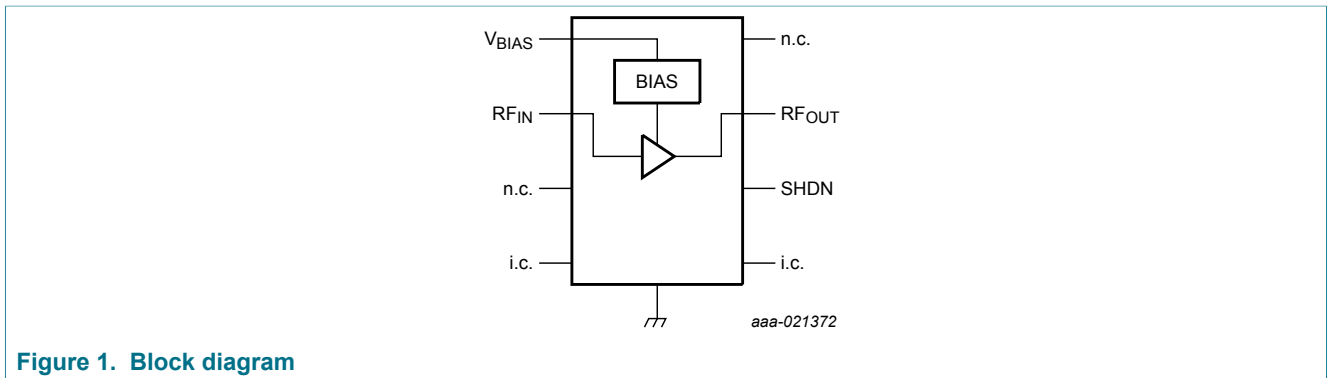


Figure 1. Block diagram

7 Pinning information

7.1 Pinning

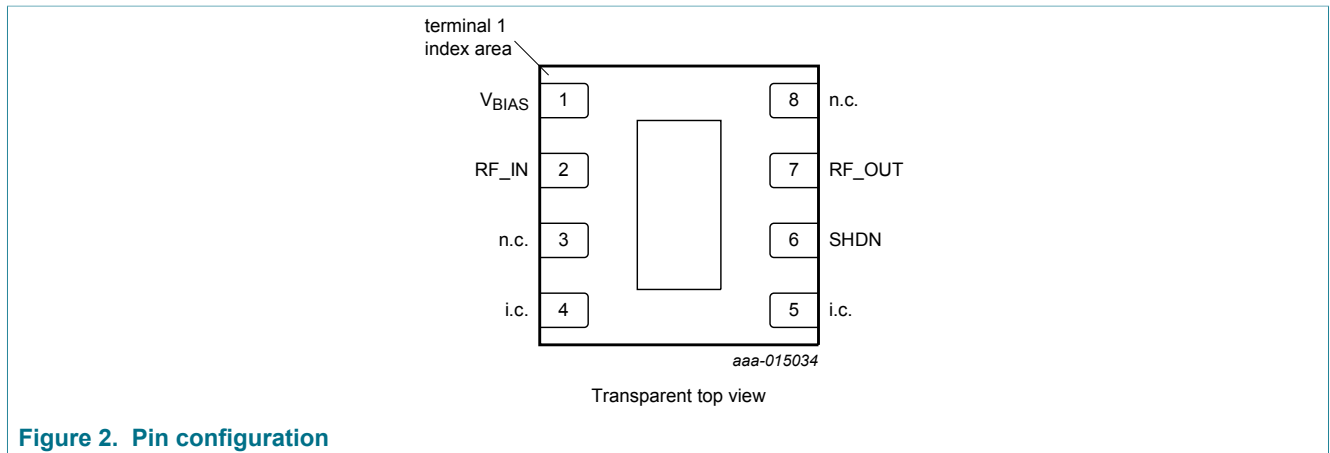


Figure 2. Pin configuration

7.2 Pin description

Table 3. Pin description

Symbol	Pin	Description
V _{BIAS}	1	bias voltage
RF_IN	2	RF input
n.c.	3, 8	not connected
i.c.	4, 5	internally connected. Can be grounded or left open in the application
SHDN	6	shutdown
RF_OUT	7	RF output
GND	exposed die pad	ground

8 Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-	6	V
V _{ctrl(sd)}	shutdown control voltage		-	3	V
I _{CC}	supply current		-	85	mA
P _{I(RF)CW}	continuous waveform RF input power		-	20	dBm
T _{stg}	storage temperature		-40	+150	°C
T _j	junction temperature		-	150	°C
P	power dissipation	T _{case} ≤ 125 °C [1]	-	510	mW
V _{ESD}	electrostatic discharge voltage	Human Body Model (HBM) According to ANSI/ESDA/JEDEC standard JS-001-2010	-	1.5	kV
		Charged Device Model (CDM); According to JEDEC standard 22-C101B	-	2	kV

[1] Case is ground solder pad.

9 Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V _{CC}	supply voltage		3.3	5	5.25	V
Z ₀	characteristic impedance		-	50	-	Ω
T _{case}	case temperature		-40	-	+85	°C

10 Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Typ	Unit
R _{th(j-case)}	thermal resistance from junction to case	[1] [2]	50	K/W

[1] Case is ground solder pad.

[2] Thermal resistance measured using infrared measurement technique, device mounted on application board and placed in still air.

11 Characteristics

Table 7. Characteristics

$f = 900$ MHz, $V_{CC} = 5$ V, $T_{amb} = 25$ °C, input and output 50Ω ; $R_{bias} = 5.1$ k Ω ; unless otherwise specified. All RF parameters are measured in an application board as shown in Figure 16 with components listed in Table 9 optimized for $f = 900$ MHz.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
I_{CC}	supply current	on state	36	48	60	mA
		off state	-	2.8	-	mA
G_{ass}	associated gain	on state	17	18.3	20	dB
		off state	-	-21	-	dB
NF	noise figure		-	0.43	0.63	dB
$P_{L(1dB)}$	output power at 1 dB gain compression		-	19	-	dBm
IP _{3O}	output third-order intercept point	2-tone; tone spacing = 1 MHz; $P_i = -15$ dBm per tone	35	39	-	dBm
		2-tone; tone spacing = 1 MHz; $P_i = -15$ dBm per tone ^[1]	33	37	-	dBm
RL _{in}	input return loss	on state	-	15.9	-	dB
		off state	-	12.5	-	dB
RL _{out}	output return loss		-	29	-	dB
ISL	isolation		-	21	-	dB
$t_{s(pon)}$	power-on settling time	$P_i = -20$ dBm; SHDN (pin 6) from HIGH to LOW ^[1]	-	1.4	-	μ s
$t_{s(poff)}$	power-off settling time	$P_i = -20$ dBm; SHDN (pin 6) from LOW to HIGH ^[1]	-	0.4	-	μ s
K	Rollett stability factor	both on state and off state up to $f = 20$ GHz	1	-	-	
$R_{pd(SHDN)}$	pull-down resistance on pin SHDN		-	10	-	k Ω

[1] For applications where fast switching is required, the value of C1 and C2 should be changed to 100 pF.

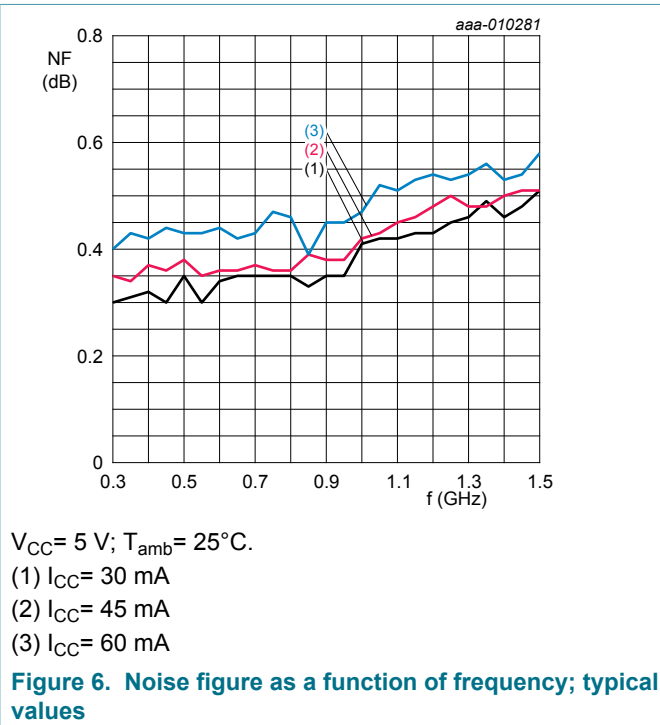
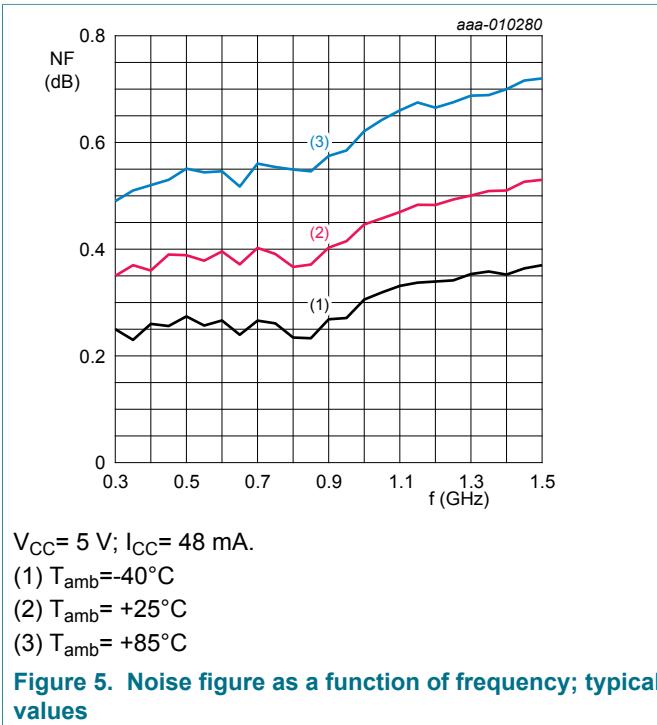
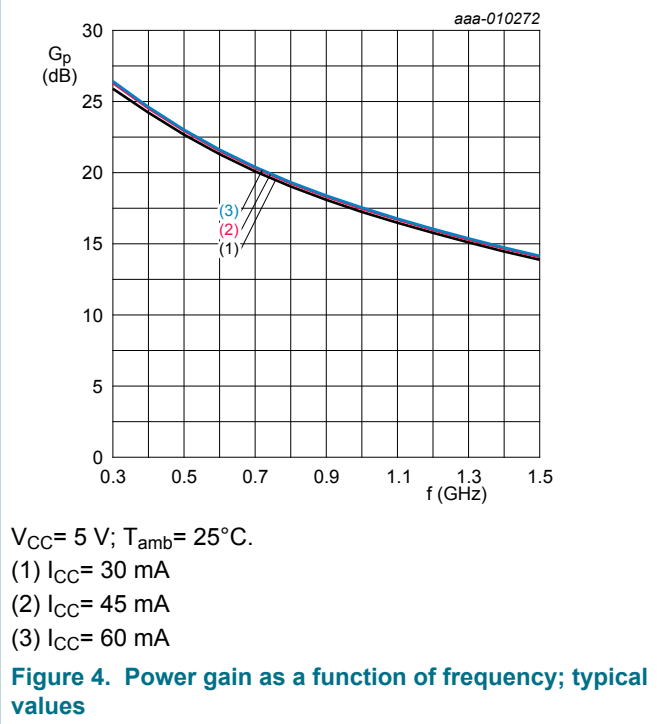
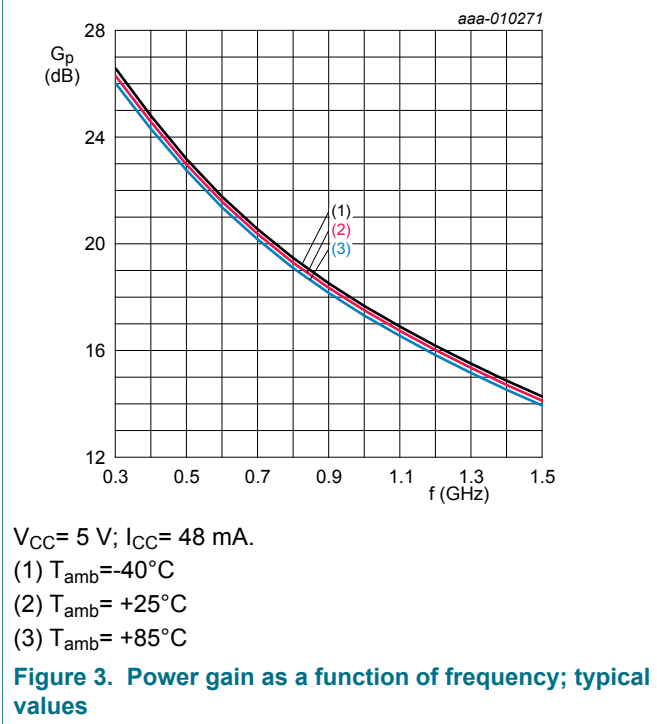
Table 8. Shutdown control

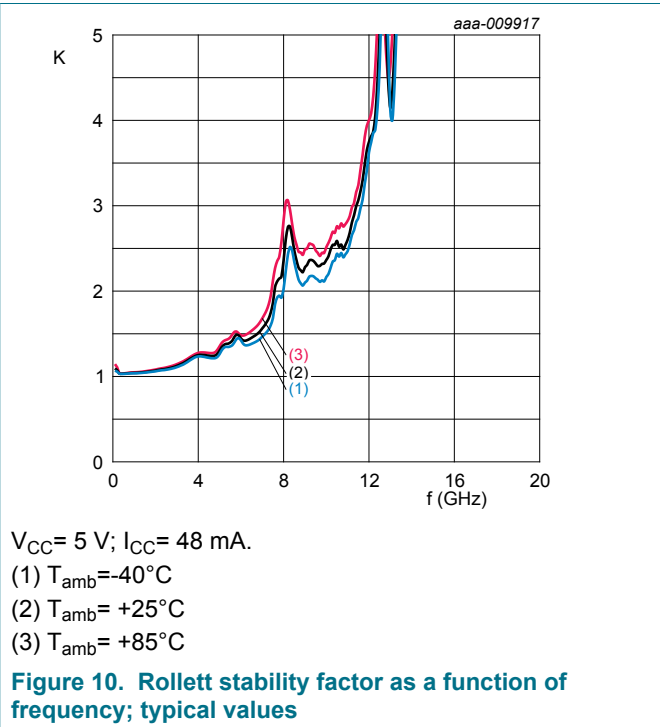
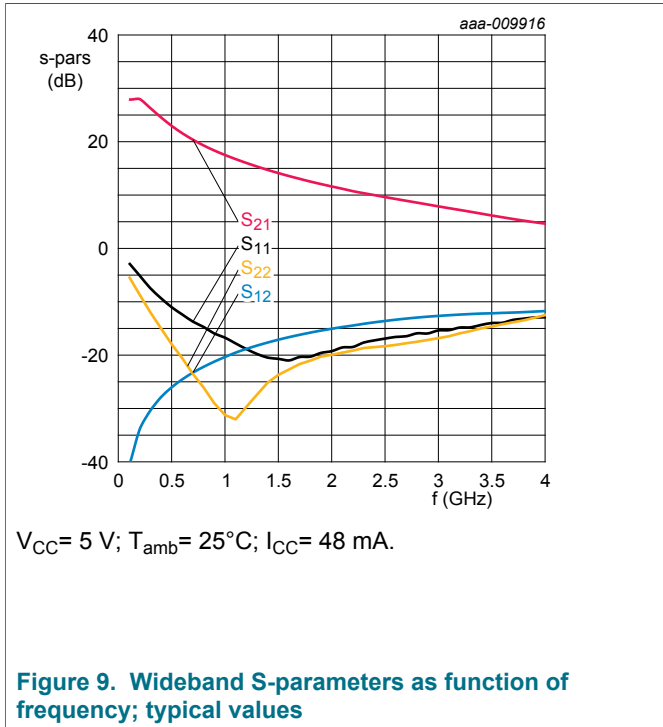
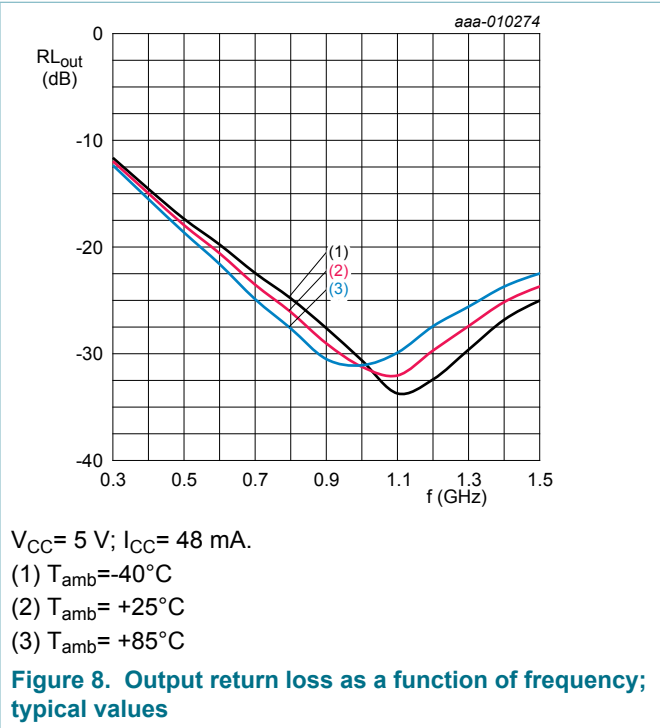
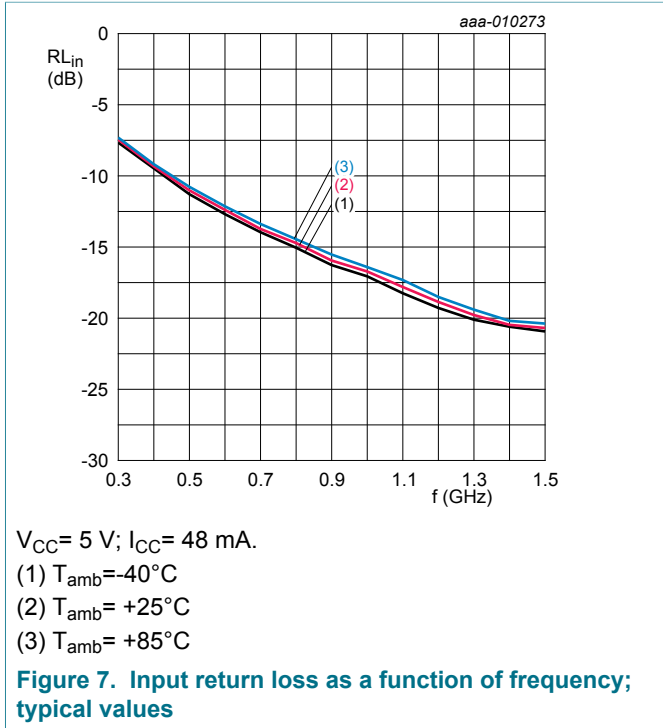
$V_{CC} = 5$ V, $T_{amb} = 25$ °C, input and output 50Ω ; $R_{bias} = 5.1$ k Ω ; unless otherwise specified. All RF parameters are measured in an application board as shown in Figure 16 with components listed in Table 9 optimized for $f = 900$ MHz.

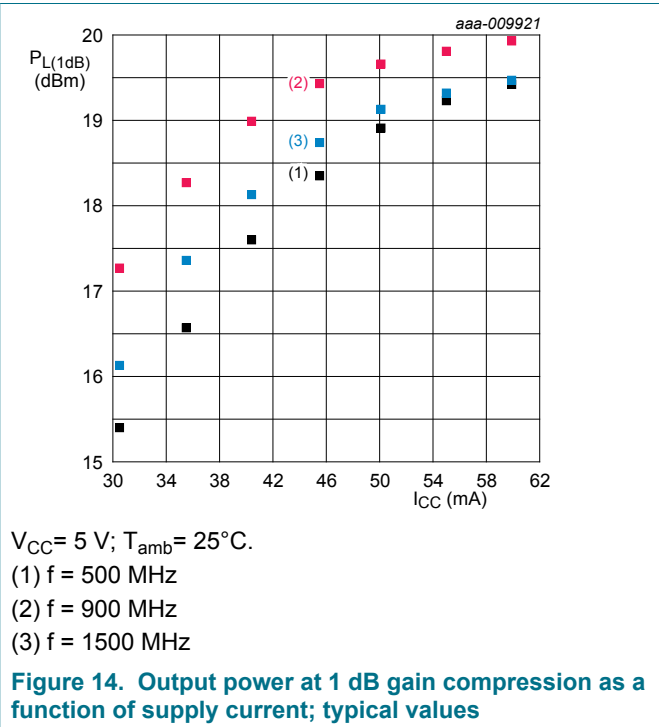
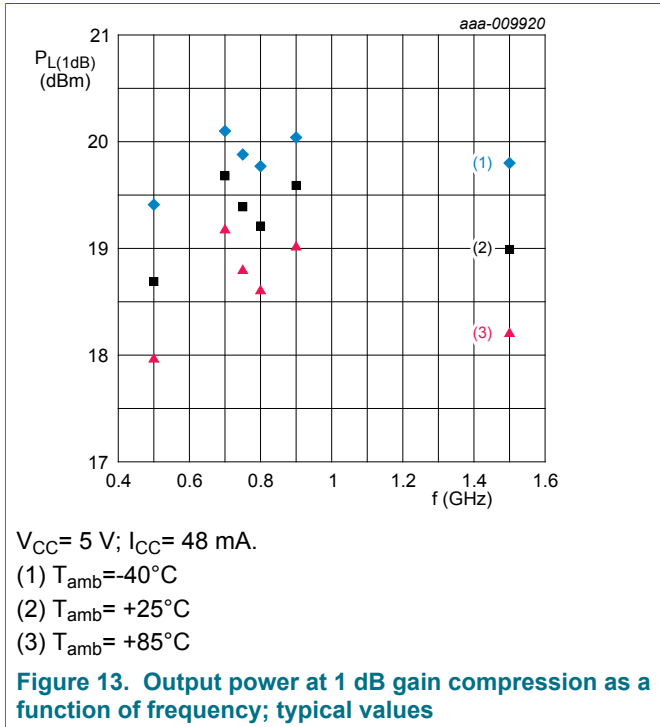
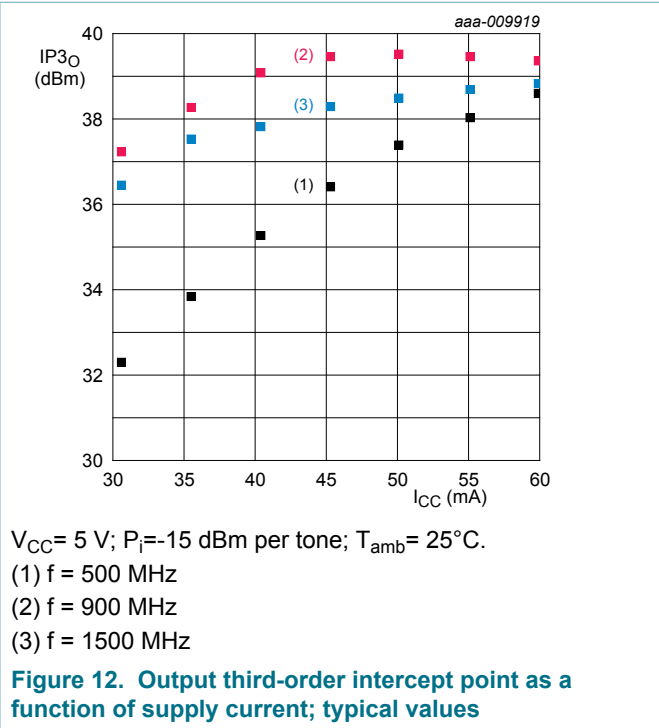
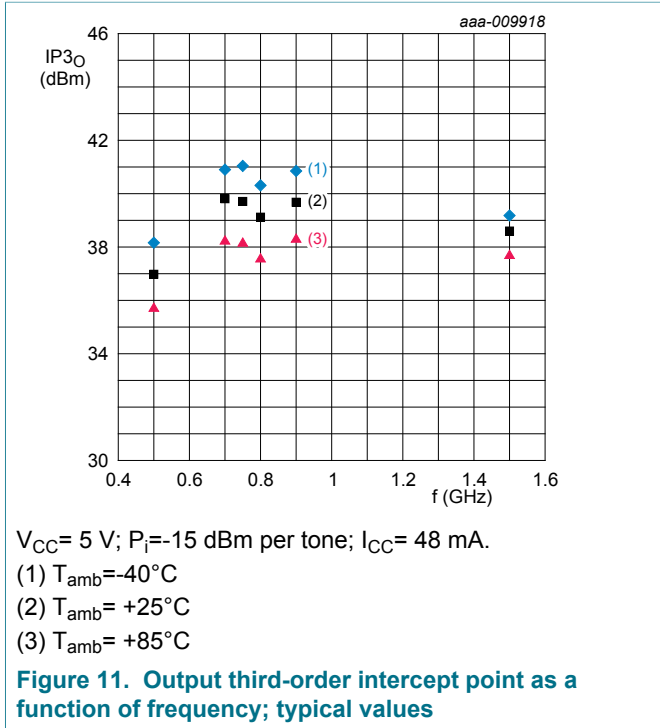
State	$V_{ctrl(sd)}$ ^[1]	Unit
on state	≤ 0.6	V
off state	≥ 1.2	V

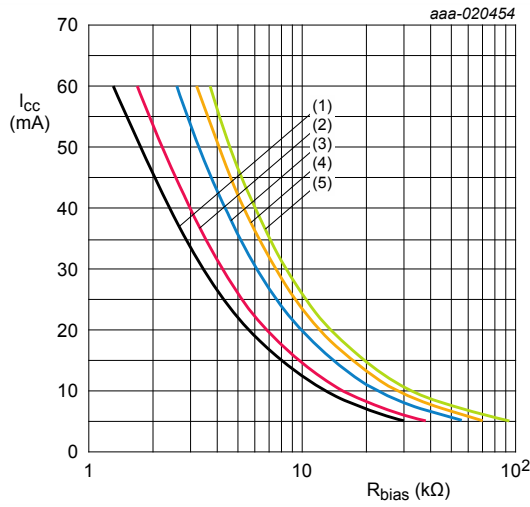
[1] Voltage on pin 6 (SHDN).

11.1 Graphics









T_{amb} = 25 °C

(1) V_{CC} = 3.0 V

(2) V_{CC} = 3.3 V

(3) V_{CC} = 4.0 V

(4) V_{CC} = 4.5 V

(5) V_{CC} = 5 V

Figure 15. I_{CC} as a function of R_{bias}; typical values

12 Application information

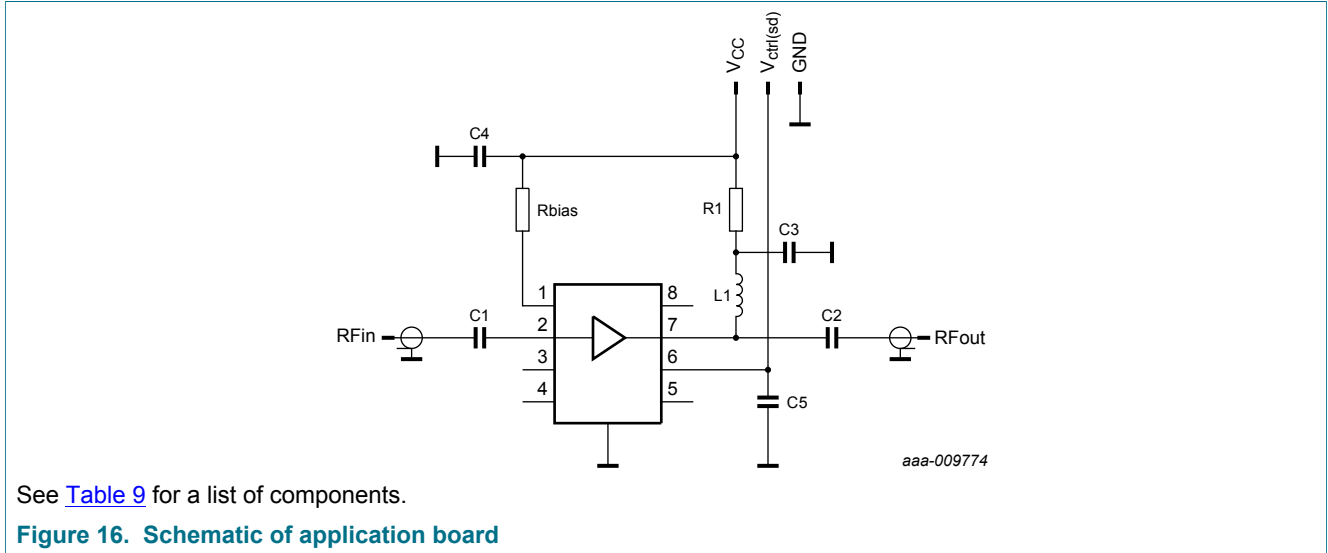


Table 9. List of components

See [Figure 16](#) for schematics.

Component	Description	Value	Remarks
C1, C2	capacitor	100 nF	
		100 pF	recommended for TDD systems
C3, C5	capacitor	10 pF	
C4	capacitor	10 nF	
L1	inductor	33 nH	
R1	resistor	10 Ω	
R _{bias}	resistor	5.1 kΩ	V _{CC} = 5 V
		2.3 kΩ	V _{CC} = 3.3 V

Table 10. Typical performance BGU8051 application board $V_{CC} = 5\text{ V}$

All RF parameters are measured at the application board as shown in [Figure 16](#) with the components as listed in [Table 9](#) while optimized for: $f = 900\text{ MHz}$, $V_{CC} = 5\text{ V}$, $I_{CC} = 48\text{ mA}$ and $T_{amb} = 25\text{ }^{\circ}\text{C}$. Unless otherwise specified.

Symbol	Parameter	Conditions	f (MHz)						
			400	500	700	750	800	900	1500
G	gain		24.6	23.0	20.4	19.8	19.3	18.3	14.1
RL _{in}	input return loss		9.3	11.0	13.7	14.2	14.7	15.9	20.7
RL _{out}	output return loss		15.0	18.0	23.5	24.8	26.1	29.0	23.7
P _{L(1dB)}	output power at 1 dB gain compression		17.9	18.8	19.8	18.7	19.4	19.4	18.5
IP _{3O}	output third-order intercept point	[1]	35.5	37.9	39.5	39.6	39.8	39.9	39.2
		[1] [2]	35.6	37.2	38.8	39.3	39.1	39.8	38.2
NF	noise figure	[3]	0.41	0.39	0.40	0.39	0.37	0.40	0.43

- [1] For 2 Tone: tone spacing = 1MHz, Po=5 dBm per tone
- [2] For applications where fast switching is required, the value of C1 and C2 should be changed to 100 pF.
- [3] Connector and board losses not de-embedded.

Table 11. Typical performance BGU8051 application board $V_{CC} = 3.3\text{ V}$

All RF parameters measured at application board shown in [Figure 16](#). The components listed in [Table 9](#) optimized for 1900 MHz; $V_{CC} = 3.3\text{ V}$; $I_{CC} = 48\text{ mA}$; $T_{amb} = 25\text{ }^{\circ}\text{C}$.

Symbol	Parameter	Conditions	f (MHz)						
			400	500	700	750	800	900	1500
G	gain		24.5	22.9	20.4	19.8	19.3	18.2	14.0
RL _{in}	input return loss		9.1	10.5	14.1	13.5	14.1	14.3	19.2
RL _{out}	output return loss		16.8	18.1	22.3	22.4	24.1	25.0	26.5
P _{L(1dB)}	output power at 1 dB gain compression		15.9	16.4	16.6	16.1	16.3	16.3	15.4
IP _{3O}	output third-order intercept point	[1]	32.4	34.3	35.5	34.5	34.1	35.3	31.6
		[1] [2]	32.4	33.1	33.6	33.6	33.1	33.2	30.2
NF	noise figure	[3]	0.39	0.40	0.42	0.43	0.44	0.44	0.43

- [1] For 2 Tone: tone spacing = 1MHz, Po=5 dBm per tone
- [2] For applications where fast switching is required, the value of C1 and C2 should be changed to 100 pF.
- [3] Connector and board losses not de-embedded.

13 Package outline

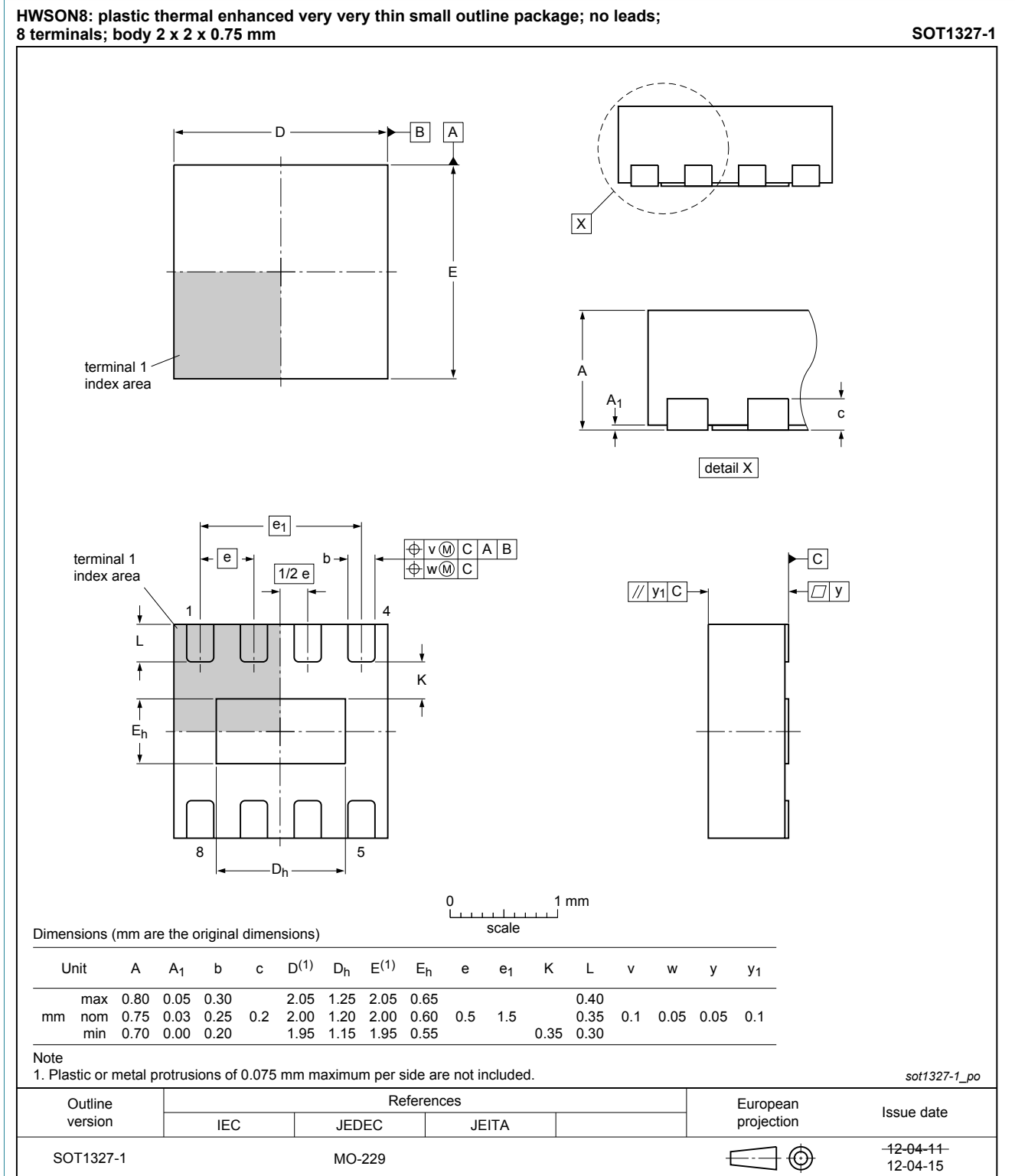


Figure 17. Package outline SOT1327-1 (HWSON8)

14 Abbreviations

Table 12. Abbreviations

Acronym	Description
CDMA	Code Division Multiple Access
ESD	ElectroStatic Discharge
FDD	Frequency-Division Duplexing
GSM	Global System for Mobile Communication
LNA	Low Noise Amplifier
LTE	Long-Term Evolution
RF	Radio Frequency
TDD	Time-Division Duplexing
W-CDMA	Wideband Code Division Multiple Access

15 Revision history

Table 13. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BGU8051 v.7	20170608	Product data sheet	-	BGU8051 v.6
Modifications:	<ul style="list-style-type: none"> • Table 4: the maximum value of V_{ESD} has been changed into 1.5 kV 			
BGU8051 v.6	20170502	Product data sheet	-	BGU8051 v.5
Modifications:	<ul style="list-style-type: none"> • Table 5 "Recommended operating conditions": the minimum value of V_{CC} has been changed into 3.3 V 			
BGU8051 v.5	20170120	Product data sheet	-	BGU8051 v.4
Modifications:	<ul style="list-style-type: none"> • Section 1 "General description": added BTS1001L according to our new naming convention 			
BGU8051 v.4	20160418	Product data sheet	-	BGU8051 v.3
Modifications:	<ul style="list-style-type: none"> • 3 V to 5 V single supply, added to Section 2 "Features and benefits" • An additional curve added to Figure "Output power at 1 dB gain compression as a function of supply current; typical values" on page 8 • Added Table 11 "Typical performance BGU8051 application board VCC = 3.3 V" on page 11 • Added Figure 1 "Block diagram" on page 2 • Added remark to R_{bias} in Table 9 "List of components" 			
BGU8051 v.3	20140929	Product data sheet	-	BGU8051 v.2
Modifications:	<ul style="list-style-type: none"> • Figure 1 on page 2: figure has been corrected 			
BGU8051 v.2	20131230	Product data sheet	-	BGU8051 v.1
BGU8051 v.1	20131127	Product data sheet	-	-

16 Legal information

16.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
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